NSN 5961-00-188-4276

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-188-4276 **Inclosure Material:** Metal **Overall Length:** 0.332 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 4.00 amperes base current, dc and 10.00 amperes collector current, dc **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**